

Local Growth of Quasicrystals

Most growth processes of physical interest are *local* in the sense that the growth probability at a given site depends only on its local (bounded) neighborhood. A recent Letter¹ claimed the discovery of a local algorithm for growing perfect Penrose tilings^{2,3} (PPT). We wish to draw attention to related work by Penrose,⁴ demonstrating that such algorithms are impossible, and to shift the focus to the study of defect formation by a more physical growth.

Using the inflation symmetry, Penrose⁴ traced the nonlocality of PPT growth to the ambiguity in Fibonacci sequences of Conway "worms,"³ which bound any forced patch of PPT.⁵ Consequently, despite its "local" classification of growth sites, the algorithm introduced in Ref. 1, *cannot* be local precisely because it generates PPT. Its first step requires going around a boundary of a PPT patch, placing all the forced tiles first.^{1,3} In the second step, a tile is attached to a 108° -corner site only after an inspection of the *entire surface* assures that no forced sites are left—a clearly nonlocal move. Except when a local growth starts on some special defective seeds,^{1,3,5} defects are necessarily created, as illustrated in Fig. 1, which was generated using an Eden growth algorithm with sticking rates $p_f = 1$, $p_{108} = 0.1$, and $p_o = 0.01$ for forced, 108° -corner, and other sites, respectively.⁶ Arbitrarily long tears⁷ appear after a sufficiently long time even for $p_o = 0$ and $p_f/p_{108} \gg 1$. While single-tile defects start appearing at times $\sim (1/p_{108})^2$, the initial growth repeatedly ceases for periods $\sim 1/p_{108}$, leading to unphysically long growth times (there is no growth in the limit $p_{108} \rightarrow 0$): Assuming $p_f/p_{108} \sim e^{60}$, it takes approximately e^{37} times longer to grow a PPT of 10^{23} tiles than a comparable periodic tiling. Most of the single-tile defects can be moved by flips of Conway worms, suggesting the importance of solitonlike dynamics in equilibration of quasicrystals. A study of formation, distribution, and relaxation of defects⁶ is essential for a resolution of the current controversy over the nature of disorder in quasicrystals.^{1,7,8}

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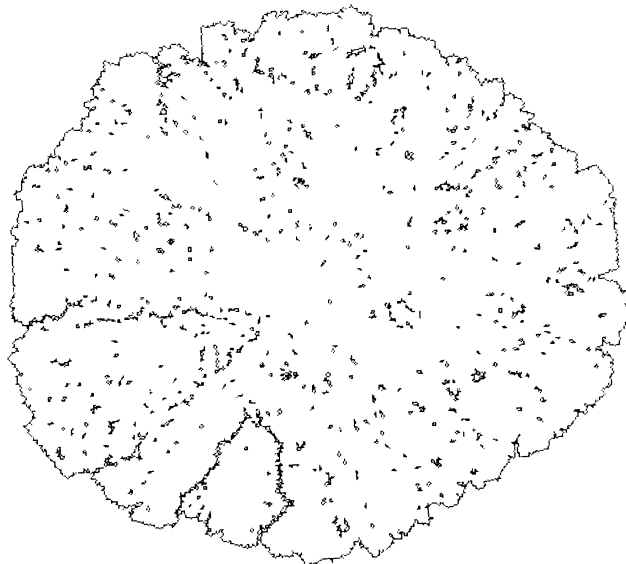


FIG. 1. A 5000-site boundary of a tiling produced by a local growth algorithm.

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